

Monday, 10 October			
Room: Imperial Main			
08:30-09:10	P1. <u>Gunnar Westin</u> Thin and ultra-thin films by solution chemistry		
	Session 1A (Imperial Main)	Session 1B (Imperial 1)	Session 1C (Imperial 2)
09:15-09:35	O-1952. <u>M. Grell</u> , T. D. Anthopoulos High electron mobility thin-film transistor enabled by solution-deposited low-dimensional metal oxide heterointerface channels	O-1753. <u>R. Mientus</u> , M. Weise, S. Seeger, J. Reck, K. Ellmer Ta-doped SnO <sub>2</sub> polycrystalline films on glass using seed-layer technique by magnetron sputtering	O-2000. F. Rigoni, C. Baratto, R. Maiti, M. Donarelli, N. Cattabiani, E. Comini, M. Ferroni, D. Zappa, A. Ponzoni, G. Sberveglieri, <u>G. Faglia</u> ZnO/graphene hybrid system: optical, electrical and gas sensing properties
09:35-09:55	O-1714. <u>N. A. Hastas</u> , H. Faber, Y-H Lin, A. D. Mottram, T. D. Anthopoulos Electronic properties of high mobility solution-processed transparent oxide transistors	O-1771. <u>L. P. Ryan</u> , A. Walsh, M. McCarthy, S. O'Brien, M. E. Pemble, I. M. Povey Atomic layer deposition of doped zinc oxide for transparent conducting layers in solar cells	O-1691. S. Sanctis, R. W. Hoffmann, <u>J. J. Schneider</u> Synthesis, chemical, structural and electrical analysis of TCO and TCO/virus hybrid materials
09:55-10:15	O-1805. <u>S. Ullah</u> , R. Branquinho, T. Mateus, R. Martins, E. Fortunato Solution combustion synthesis of transparent & conducting thin films with substituted or reduced use of indium for photovoltaic applications	O-1723. <u>E. Rucavado</u> , F. Landucci, Q. Jeangros, J. Holovsky, A. Hessler-Wyser, M. Morales-Masis, C. Ballif Correlation between sub-gap states and optoelectronic properties of amorphous zinc tin oxide	O-1995. <u>E. Gagaoudakis</u> , G. Michail, E. Aperathitis, V. Binas, M. Eleftheriou, E. Poulakis, G. Kiriakidis Low Temperature RF-Sputtered VO <sub>2</sub> Thermochromic Films for Smart Window Applications
10:15-10:45	I-2044. <u>M-H Yoon</u> Sol-gel metal oxide material-based electronics: low-temperature photoactivation, large-area printing, and direct patterning	I-1940. <u>M. Modreanu</u> Investigation of optical and vibrational properties of functional metal oxides	I-1860. <u>C. Baratto</u> Nanophotonic and plasmonic for chemical sensing
10:45-11:15	Coffee break		
Room: Imperial Main			
11:15-11:55	P2. <u>Gerwin Gelinck</u> Flexible amorphous oxide semiconductor thin-film transistors		
	Session 2A (Imperial Main)	Session 2B (Imperial 1)	Session 2C (Imperial 2)
12:00-12:20	O-1821. <u>P. B. Pillai</u> , M. M. De Souza Memory and Learning behaviour of ZnO based transparent synaptic thin film transistors	O-1872. <u>J. Resende</u> , S. Brochen, L. Bergerot, C. Jiménez, N. D. Nguyen, J. L. Deschanvres Cation-doped Cu <sub>2</sub> O as a transparent p-type semiconducting oxide with enhanced performances: A comparison between strontium and magnesium incorporation	O-1987. <u>C. Petridis</u> , D. Konios, M. M. Stylianakis, E. Stratakis, E. Kymakis Solution-processed reduced graphene oxide electrodes for organic photovoltaics
12:20-12:40	O-1839. <u>C. Fernandes</u> , A. Kiazadeh, E. Fortunato, R. Martins, P. Barquinha Low temperature amorphous ZTO TFTs on flexible substrates using a combinatorial approach	O-2006. <u>G. Kakavelakis</u> , D. Konios, C. Petridis, E. Stratakis, E. Kymakis Work function tuned solution processable graphene derivatives as buffer layers for high efficient organic and perovskite solar cells	O-1938. <u>A. Varea</u> , S. Claramunt, D. López-Díaz, M. M. Velázquez, A. Corneta, A. Cirera The interband importance of the first-order raman spectrum of graphene oxide
12:40-13:10	I-2074. <u>L. Pereira</u> , L. Santos, P. Grey, J.T. Carvalho, D. Gaspar, E. Fortunato, R. Martins Oxide nanoparticles based electrical and electrochemical devices on paper substrates	I-2065. T. Sannicolo, M. Lagrange, S. Xian, D. Muñoz-Rojas <sup>1</sup> , C. Jiménez <sup>1</sup> , Y. Bréchet, N. D. Nguyen, <u>D. Bellet</u> Transparent electrodes based on silver nanowire networks: from fundamental aspects to integration into device	I-1707. <u>S-H Choi</u> Use of graphene in optoelectronic devices as a transparent electrode
13:10-15:00	Light lunch and poster session 1		

	<b>Room: Imperial Main</b>		
15:00-15:40	<b>P3-2052. <u>George Malliaras</u></b> Interfacing with the brain using organic electronics		
	<b>Session 3A (Imperial Main)</b>	<b>Session 3B (Imperial 1)</b>	<b>Session 3C (Imperial 2)</b>
15:45-16:05	O-1754. <u>K. A. Stewart</u> , J. F. Wager AOS TFT mobility limits considerations	O-1996. <u>M. M. Stylianakis</u> , D. Konios, P. Tzourmpakis, C. Petridisa, E. Kymakis Ternary organic solar cells incorporating 2D materials	O-1977. <u>V. Skoulas</u> , A. Papadopoulos, G. D. Tsididis, E. Stratakis Ultrafast laser processing of transparent materials for the fabrication of biomimetic surfaces
16:05-16:25	O-1960. <u>H. Ma</u> , G. Yao, A. Kunrath, A. Nathan Fabrication and characterisation of zinc oxynitride for thin film transistors	O-1784. <u>S. L. Moffitt</u> , Q. Zhu, Q. Ma, D. Bruce Buchholz, R. P. H. Chang, T. O. Mason, T. J. Marks, M. J. Bedzyk Developing structure-property relationships in amorphous transparent conducting oxides through local structure studies of the In-Ga-O system	O-1949. <u>C. Kim</u> , Y. Won, S. Kim, S. E. Kim Comparative analysis of SnO <sub>2</sub> thin films deposited by reactive sputtering in different SnO/Sn target compositions
16:25-16:45	O-1701. <u>Y. Zhang</u> , Z. Mei, S. Cui, H. Liang, Y. Liu, X. Du Flexible transparent field-effect diodes fabricated at low-temperature with all oxide materials	O-1950. <u>L. M. Garten</u> , J. Waters, I. Ferrall, L. T. Schelhas, M. F. Toney, B. Gorman, P. Ndione, S. Lany, A. Zakutayev, D. Ginley Doping studies of gallium oxide wide band Gap semiconductors	O-2008. <u>P. Lunca Popa</u> , J. Crépellière, N. Bahlawane, R. Leturcq, D. Lenoble Thermoelectric properties of highly conductive p-type CuCrO <sub>2</sub> thin films grown by metal-organic chemical vapour deposition
16:45-17:15	I-2060. <u>P. Barquinha</u> , C. Fernandes, D. Lima, J. Martins, A. Rovisco, A. Kiazadeh, R. Branquinho, E. Carlos, D. Salgueiro, P. Bahubalindrani, R. Martins, E. Fortunato Flexible oxide electronics: getting multifunctionality, sustainability and speed altogether	I-2059. <u>M. Higashiwaki</u> , M. H. Wong, K. Konishi, K. Sasaki, K. Goto, R. Togashi, H. Murakami, Y. Kumagai, B. Monemar, A. Kuramata, S. Yamakoshi Recent Advances in Ga <sub>2</sub> O <sub>3</sub> power device technologies	I-2024. <u>T. Deppisch</u> , N. Morrison, C. Kurthen, U. Hermanns, D. Wagner, R. Kukla Advanced R2R touch panel manufacturing solutions
17:15-17:45	<b>Coffee break</b>		
	<b>Room: Imperial Main</b>		
17:45-18:25	<b>P-1980. <u>Andreas Klein</u></b> Electric properties of grain boundaries in transparent oxide conductors		
	<b>Session 4A (Imperial Main)</b>	<b>Session 4B (Imperial 1)</b>	<b>Session 4C (Imperial 2)</b>
18:30-18:50	O-2201. <u>T. Fischer</u> , S. Mathur In-situ characterisation during fabrication of nanostructured functional thin films via chemical vapour deposition	O-1966. <u>J. Jiang</u> , Y. Lu, B. Kramm, F. Michel, C. T. Reindl, M. Kracht, B. K. Meyer, D. M. Hofmann, M. Eickhoff Nitrogen incorporation in SnO <sub>2</sub> thin films grown by chemical vapor deposition	O-2004. <u>C. Tsangarides</u> , H. Ma, A. Nathan Inkjet-printing fabrication of pedot:PSS-based thermoelectric modules
18:50-19:20	I-2043. <u>H. E. Unalan</u> Metal nanowire networks as transparent contacts	I-1975. <u>E. Stratakis</u> Laser processing of 2D nanosheet based materials for organic electronics	I-2014. <u>S. Logothetidis</u> Novel R2R fabrication process for high quality transparent electrode nanolayers for cost effective manufacturing of flexible organic photovoltaics
19:20-21:00	<b>Dinner</b>		
21:00-22:00	<b>TCM-net Board meeting</b>		